From Microscopic to Macroscopic Description of Composite Thin Panels: A Road Map for Their Simulation in Time Domain

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Abstract—In this paper, we show a simulation strategy for composite dispersive thin-panels, starting from their microscopic characteristics and ending into a time-domain macroscopic model. In a first part, we revisit different semianalytic methods that may be used to obtain the S-parameter matrices. The validity of them is assessed with numerical simulations and experimental data. We also include some formulas that may be used to tailor the shielding effectiveness of panels in a design stage. In a second part, we present an extension to dispersive media of a subgridding hybrid implicit–explicit algorithm finite difference time domain (FDTD) devised by the authors to deal with that kind of materials. The method, here presented and applied to the FDTD method, is a robustly stable alternative to classical impedance boundary condition techniques. For this, a previous analytical procedure allowing to extract an equivalent effective media from S-parameters is presented, thus making this road map able to simulate any kind of dispersive thin layer. A numerical validation of the algorithm is finally shown by comparing with experimental data.

Index Terms—Finite difference time domain (FDTD), implicit–explicit schemes, subcell models, thin-layer modeling, time domain (TD).

I. INTRODUCTION

THE ADEQUATE simulations of the electromagnetic (EM) properties of composite multilayered complex thin-panels are of extreme importance, since they are part of modern materials used, e.g., in the automotive or aeronautical industries. The challenge emerges because of the multiple scales which are involved, being impossible in practice to mix microscopic and macroscopic geometrical features in a single simulation. A typical workflow to approach this type of problems can be sectioned in two stages: the EM modeling of the thin-panel properties and the incorporation of this model into a numerical solver. In a first stage, our concern is to obtain an accurate EM characterization of the thin-panel transmission and reflection properties for normal incidence as a function of frequency. We can distinguish three different procedures to obtain these parameters: to perform experimental measurements with standard setups such as ASTM D4935 or its variants [1]–[3], to derive analytical formulations accounting for its microscopic structure [4]–[6], or to carryout simulations of the unit cell with appropriate periodic boundary conditions [6]–[8]. These results can be typically expressed in two frequency-dependent matrix forms: transmission matrices (ABCD) and S-parameters, both linked by well-known equivalence relations [9].

In a second stage, the treatment of the obtained S-parameters depends on the method to be used by the solver. A common approach to this problem is to treat each thin-panel by impedance boundary conditions (IBCs) to avoid costly fine meshings of the material structure. In the frequency domain (FD), the introduction of IBCs is similar to classic BCs such as perfect electrically/magnetically conducting, and the macroscopic parameters can be used with little or no treatment, directly modifying the BCs on the element surfaces accordingly. In time domain (TD), on the contrary, these parameters cannot be used directly and require the extraction of appropriate dispersive models. Specifically within the framework of the finite difference time-domain (FDTD) method, a typical approach consists of using a technique known as network IBC (NIBC) [4], [10]. For this, a partial fraction expansion, in terms of complex-conjugate pole–residue pairs, is performed by fitting the frequency-dependent S-parameters, e.g., by using a vector-fitting (VF) technique [11]. However, the poles need to be carefully chosen to avoid instabilities, and, even in this case, late-time instabilities are reported to appear because of the nonallocated nature of FDTD [12], [13]. To overcome these limitations, in [14], we proposed a novel technique based on a robustly stable subgridding boundary condition (SGBC), which does not present the late-time instabilities of NIBC. The method was based on a hybrid implicit–explicit (HIE) combination of the classical FDTD with a Crank–Nicolson time-domain (CNDT) unconditionally stable method. However, the formulation presented in [14] required to know the multilayer interior structure of the thin panel,
in terms of its bulk conductivity and the thickness of each layer. As a consequence, that approach could not be used to model arbitrarily dispersive thin-panels, and it has been extended to this end.

In this paper, we extend the contribution made in [15] and present a full road map which starts from the S-parameters, found either by simulation or by semianalytical methods and finishes with a dispersive set of constitutive parameters that can be efficiently simulated by FDTD by using the SGBC method. The rest of this paper is organized as follows. In Section II, we present a discussion on the available analytical models for the panels and discuss which ones are preferable for different configurations. We also present a discussion on the factors that dominate the SE behavior of the panels which may be useful, for instance, to decide on the optimal materials, densities, or shapes of a fiber. To validate these analytical models, in Section IV, we cross-compare with results from simulations of their microscopic structure. In Sections V and VI, we briefly describe how to find a suitable TD model in terms of constitutive parameters, and we extend the SGBC method to deal with arbitrarily dispersion by generalizing the unconditionally stable CNTD to dispersive media. Finally, we present a simple validation with experimental data where we have followed the whole road map described in this paper.

II. Thin Panel Modeling

Let us start our discussion by defining some basic concepts that will help us to fix a notation. When a harmonic plane-wave, having an incident electric field amplitude $E^i$, illuminates perpendicularly a flat panel, part of it is reflected ($E^r$), and part of it gets transmitted through it ($E^t$). In consequence, thin panels can be regarded as multiport networks, identifying port 1 as the side of the panel illuminated by the plane-wave and port 2 as the side where the wave is transmitted

$$ \begin{bmatrix} E_2 \\ H_2 \end{bmatrix} = [\Phi] \begin{bmatrix} E_1 \\ H_1 \end{bmatrix} = \prod_{i=1}^{N_l} [\Phi_i] \begin{bmatrix} E_1 \\ H_1 \end{bmatrix} \quad (1) $$

with $\Phi$ and $\Phi_i$ being the transmission ($ABCD$) matrix of the thin panel and of the stacked layers composing it, respectively. The scattering parameters can be derived from matrix $\Phi$, using, for instance, the relations given in [9].

For panels in free-space, characterized by an intrinsic impedance $\eta_0$, we can obtain the transmission coefficient as

$$ T = S_{21} = \frac{2\eta_0}{\Phi_{11}\eta_0 + \Phi_{12}\eta_0^2 + \Phi_{22}\eta_0} \quad (2) $$

For anisotropic media, we have to account for TE$_\zeta$ and TM$_\zeta$ polarizations, henceforth simply TE and TM. We can identify four transmission matrices for TE and TM conversions

$$ \begin{bmatrix} E_{TE}^2 \\ H_{TE}^2 \\ E_{TM}^2 \\ H_{TM}^2 \end{bmatrix} = \begin{bmatrix} [\Phi_{TE\rightarrow TM}] & [\Phi_{TE\rightarrow TE}] \\ [\Phi_{TM\rightarrow TE}] & [\Phi_{TM\rightarrow TM}] \end{bmatrix} \begin{bmatrix} E_{TE}^1 \\ H_{TE}^1 \\ E_{TM}^1 \\ H_{TM}^1 \end{bmatrix} \quad (3) $$

and regard them as four independent two-port networks, one for each of the possible mode conversions. Proceeding with each of them in a similar way as for isotropic media, we can obtain the four S-parameters for inter- and intramodal transmission coefficients.

A typical parameter often used is the shielding effectiveness (SE), as a measure of the capability of the panel to shield an enclosure from the EM environment. It is defined as the inverse of the transmission coefficient

$$ SE = \frac{1}{T} = \frac{|E^t|}{|E^i|} \quad (4) $$

Though the method presented in the following can in general find the S-parameters, we will henceforth just focus in the SE. Note that (4) is a scalar and sufficient for isotropic media. However, for anisotropic media, a TE wave can have transmitted TM and TE components, $T_{TE\rightarrow TM}$ and $T_{TE\rightarrow TE}$, respectively, and we can define an average SE by

$$ SE_{av} = \frac{2}{|T_{TM\rightarrow TM}| + |T_{TE\rightarrow TE}|} \quad (5) $$

III. Periodic Materials Based on Conductive Meshes

Modern composite materials consist often in multilayered structures including woven/nonwoven carbon fibers (CFC), reinforcing wire-meshes, solid or expanded metal foils, honeycombs, and so on embedded in some matrix material (prepreg resins and so on). In what follows, we will focus ourselves to periodic reciprocal media, as a model of woven carbon fiber composites and reinforcing wire meshes. For this media, we will adopt the more convenient notation shown in Fig. 1 to refer to the electric components of the TE and TM modes as $E_\psi$ and $E_\zeta$, respectively. We will next revisit two of the most well-known methods to analyze these media: the Holloway and the Wait models.

A. Holloway’s Model

Holloway et al. [6] propose and analyze three different models for carbon-fiber composites. These are composed of
layers characterized with a thickness $L$, with round fibers of diameter $D$ which repeat with a periodicity $P$ [6, Fig. 1]. The fibers have a permittivity $\varepsilon_f$ and permeability $\mu_f$ and are assumed to be surrounded by the matrix bulk material forming the remainder of each layer with $\varepsilon_b$ and $\mu_b$. The fiber composite layer is decomposed in several regions. In each of these regions, the effective permittivity tensor $\tilde{\varepsilon}$ is calculated as

$$\tilde{\varepsilon}_{ij} = \varepsilon_{ij} \delta_{ij}$$ \hspace{1cm} (6)

with

$$\varepsilon_{zz}^{-1} = (1 - g)\varepsilon_b^{-1} + g\varepsilon_f^{-1}$$ \hspace{1cm} (7)

$$\varepsilon_{yy} = \varepsilon_{xx} = (1 - g)\varepsilon_b + g\varepsilon_f$$ \hspace{1cm} (8)

and $g$ being a geometric parameter depending on the particular shape of the fibers. A similar formula could be obtained for the effective permeability tensor. Transmission matrix coefficients can be straightforwardly obtained from the stacking of layers with these anisotropic permittivity and permeability tensors rotated accordingly to the fiber orientation [16].

The model predictions are compared there with results obtained from finite element method (FEM) simulations. From them, the authors conclude that their so-called three-layer inhomogeneous model, referred hereafter as Holloway’s model, provides the best results for frequencies in which $P/\lambda < 1$. At frequencies below the skin depth of an equivalent conductive layer, the model matches the expected results. At higher frequencies, the model will still produce accurate results, when the conducting fibers are closely packed, and the proximity effects dominate over inductive and skin effects such as the ones discussed in Section III-B. This proximity effect is caused by conduction time-varying currents inside the wires which create nonnegligible eddy currents in their neighbors. Similar to the skin effect, this effectively increases their total impedance. This effect becomes more important when several layers of wires are stacked closely and has been studied in detail in the context of the transformer windings used in electric engineering [17], [18].

### B. Wait’s Model

Wait [5] obtains the following expression for the surface impedance presented by an array of wires. The assumptions made to obtain such formula are that there are no resonances within the wire or on its surface ($\lambda \gg a$), and as long as the distance between wires compared with their radius is sufficiently high to avoid proximity effects, i.e., $P \gg a$

$$Z_S = Z_wP + j\eta_0 \frac{P}{\varepsilon_b} \log \frac{P}{\pi a}$$ \hspace{1cm} (9)

The sheet impedance can be used with the transmission matrix formalism in the following way [4]:

$$\begin{bmatrix} E_{\psi}(a/2) \\ H_{\zeta}(a/2) \\ E_{\zeta}(a/2) \\ H_{\psi}(a/2) \end{bmatrix} = [\Phi_1] \begin{bmatrix} E_{\psi}(-a/2) \\ H_{\zeta}(-a/2) \\ E_{\zeta}(-a/2) \\ H_{\psi}(-a/2) \end{bmatrix}$$ \hspace{1cm} (10)

with

$$[\Phi_1] = \begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & 1 & 0 & 0 \\ 0 & 0 & 1 & 0 \\ 0 & 0 & 1/\varepsilon_f & 1 \end{bmatrix}$$ \hspace{1cm} (11)

In [4], metallic meshes and expanded foils are modeled using (11). The stacking of several layers is a valid approach when then interactions between different wire grids can be neglected. This will be true if the wire grids are perpendicular; however, if several layers of aligned wire grids are stacked, the effective periodicity is reduced and this results in proximity effects not being negligible, invalidating the model.

### IV. Validation With Fine-Structure Simulations

In this section, we will discuss the validity of the presented models. To do so, the periodic microscopic pattern of several geometries is simulated with an FEM FD tool, Ansys HFSS, in the range between 0.1 and 100 GHz; and the results are compared with Holloway and Wait’s predictions. Note that a TD simulator is not efficient performing these microscopic simulations as the space-step necessary to properly resolve these geometries would be approximately $1 \mu$m, therefore imposing a time-step which does not allow us to obtain low-frequency results in an acceptable number of iterations. The structures have been chosen as representative of four common situations found in materials used in the industry: two wire meshes, one dense and one nondense, with no ohmic connection between different wires, an expanded metal foil with ohmic connections at the metal intersections, and a one-layer single-orientation CFC material. For all the cases considered, we will assume that the materials are embedded in free-space as the effect of resin materials (nonconductive and with a low permittivity) is negligible for fibers of the conductivity considered here.

#### A. Loose Wire Mesh

Let us start by modeling a loose wire mesh [Fig. 2(a)] consisting of two arrays of parallel wires and forming an angle of 89°. This panel was obtained from [4] (S1) and was modeled with two layers of wires having $a_1 = a_2 = 50 \mu$m, $\sigma = 58$ MS/m, and $P_1 = P_2 = 558 \mu$m. In this case, wires are widely separated ($P/a \approx 11$) and therefore we can expect the inductive effects to dominate. As expected, we obtain a good match between simulations and Wait’s model (Fig. 3), with differences of less than 0.5 dB. Holloway’s model fails for this case as it does not take into account inductive effects, and proximity effects are negligible. Experimental data for the SE of this test case are also shown in Section VII compared with FDTD results found after Wait’s prediction for the macroscopic S-parameter matrix.

#### B. Expanded Foil

The second test-case is an aluminum expanded foil [Fig. 2(b)], similar to the ones presented in [4]. In this case,
we have three significant differences with respect to the previous case: intersection points now have ohmic connectivity, wire sections are not round, and the lines are forming an angle of $57.16^\circ$. For their incorporation into the analytical models, the rectangular cross sections of the expanded foil were substituted by area-equivalent round wires with $a = 90 \, \mu m$ and $\sigma = 38 \, MS/m$. With this geometrical data, we can draw a unit cell with periodicities of $W = 2129 \, \mu m$ and $H = 1259 \, \mu m$. The periodicities of the two layers used in the models were $P = 1089 \, \mu m$. Similar to the case in Section IV-A, the Holloway’s model does not provide good predictions, due to the lack of validity of the effective layer approximation (Fig. 4). Wait’s model predicts an average SE about 3 dB lower, likely due to the overestimation of impedance in the wire intersections.

C. Dense Wire Mesh

We now aim to test the model with a dense stainless steel mesh [Fig. 2(c)] in which the $P/a \approx 1$. To model this setup, we use two perpendicular arrays of wires with $a_1 = 100 \, \mu m$, $a_2 = 35 \, \mu m$, $\sigma = 37 \, kS/m$, $P_1 = 135 \, \mu m$, and $P_2 = 35 \, \mu m$. Results (Fig. 5) show some agreement between Wait and Holloway’s models at low frequencies but fail at higher frequencies. A reason for this is that when the wires
are too close to each other, there is a dominance of the prox-
imity effects, which are eventually overcome by the inductive
behavior of the grid. This mixed behavior seems to indicate
that possibly a hybrid model combining the Holloway’s and
Wait’s approach can provide optimal results for this type of
configurations.

D. Carbon Fiber Composites

Finally, woven CFC composite panels are among the most
used materials in modern industry. These panels are created
by the weaving of several sublayers of fibers with one or dif-
ferent orientations. Each of these sublayers is composed of
tows, each containing thousands of fibers. The microscopic
structure of a typical CFC layer [Fig. 2(d)] has been modeled
for our simulation by stacking 24 sublayers of fibers with
\( a = 5.2 \, \mu m \), \( \sigma = 66.667 \, kS/m \), and \( P = 6.76 \, \mu m \).
Odd and even sublayers are displaced \( P/2 \) in the \( y \)-axis,
therefore leaving a distance of \( P\sqrt{3}/2 \) between them. For this,
we have just made simple assumptions based on the single
fiber radius, and the volume density fiber provided by the
manufacturer. Just a single-layer single-orientation model has
been analyzed, though usual panels may have up to several
tenths of layers with different orientations, making them dif-
ferent both to simulate and to measure. Simulation and model
results (Fig. 6) show that, as we may expect, the proximity
effects dominate not only because of the neighbor fibers in
the same sublayer but due to the ones in the neighboring
sublayers which have the same orientation. As a consequence,
the field cannot penetrate more than a few microns into the
CFC at high frequencies (Fig. 7). While all models agree at
low frequencies, Holloway’s matches simulated results with a
deviation of approximately 2 dB in the range of frequencies
studied. We can compare this result with the ones obtained for
an equivalent 76-\( \mu m \) bulk layer of material which presents
a much larger deviation. We can also conclude that Wait’s
model is not effective to study this type of structures, due to
the dominance of the proximity effects. It bears noticing that
we have assumed the CFC to have a homogeneous stacked
distribution of the carbon fibers, and we have neglected any
weaving fabric geometrical features. In practice, the weaving
will interrupt the spatial homogeneity of the fibers clustering
them in warps with some separation among them, which will
create an inductive point of entry of EM energy. This will
compete with the shielding provided by each individual warp
due to their internal proximity effect dominance.

V. FINDING A TD MODEL

Holloway and Wait’s techniques described in the previous
sections permit us to find the whole S-parameter matrices for
different material arrangements starting from their microscopic
structure. We can incorporate their behavior into numerical
methods by means of NIBC, as described in [10], or by
the novel SGBCs introduced by Cabello et al. [14], [15].
The latter approach has proven to exhibit a superior late
time stability compared with the NIBC method. However, the
S-parameters must be first transformed into bulk constitutive
complex permittivity and permeability effective parameters
\( \varepsilon_{\text{eff}} \) and \( \mu_{\text{eff}} \), for some given thickness, to be used by
SGBC.

Bulk parameter retrieval from S-parameters remains an
active topic of research [19]. In this paper, we will just briefly
summarize the procedure that we have adopted, based on
the work of [20]. For this, let us assume for simplicity a
nonmagnetic, isotropic, left-right symmetric (\( S_{11} = S_{22} \)), and
reciprocal material (\( S_{12} = S_{21} \)). The relationship between
the S-parameters under normal incidence and the effective
permittivity can be expressed as
\[
S_{11} = R \frac{1 - \psi^2}{1 - R^2 \psi^2} \\
S_{21} = \frac{(1 - R^2) \psi}{1 - R^2 \psi^2}
\] (12)
with
\[
R = \frac{\eta_{\text{eff}} - \eta_0}{\eta_{\text{eff}} + \eta_0}
\] (13a)
\[
\psi = e^{-j n_{\text{eff}} k_0 t_h}
\] (13b)
where \(k_0 = \omega/c_0\) is the free-space wavenumber, \(\eta_0 = (\mu_0/c_0)^{1/2}\) is the free-space impedance, and \(\eta_{\text{eff}} = (\mu_{\text{eff}}/\varepsilon_{\text{eff}})^{1/2}\) that of the effective medium. \(t_h\) stands for the material thickness. There is a degree of freedom to choose this parameter, which does not necessarily need to match the actual physical thickness. Different bulk constitutive parameters will be found for slabs with different \(t_h\) values, all with the same S-parameters. From (12) and (13b), the procedure is as follows:

1. The effective impedance is found after some algebra by
\[
\eta_{\text{eff}} = \pm \eta_0 \sqrt{\frac{(1 + S_{11})^2 - S_{21}^2}{(1 - S_{11})^2 - S_{21}^2}}
\] (14)
where according to [19], any choice of the sign is equally valid (some authors also use a passivity condition to keep just one of them).

2. The effective refractive index is next found by
\[
n_{\text{eff}} = j \frac{\log \psi}{k_0 t_h} = \left( j \frac{\log |\psi|}{k_0} - \frac{\psi + 2 \pi m}{k_0} \right) \frac{1}{t_h}
\] (15)
with
\[
\psi = \frac{S_{21}}{1 - S_{11}} \quad \text{and} \quad \Gamma = \frac{\eta_{\text{eff}} - \eta_0}{\eta_{\text{eff}} + \eta_0}.
\] (16)
Note that the refractive index admits infinite solutions for its real part depending on the integer number \(m\), each one corresponding to a branch of the complex logarithm. This fact introduces an added difficulty that has attracted a lot of research efforts since the original works of [21] and [22].

3. The \(\varepsilon_{\text{eff}}\) can now be found from (14) and (15); however, the assumption of a nonmagnetic material releases us from solving the branch problem, since \(\varepsilon_{\text{eff}}\) can be directly found by
\[
\varepsilon_{\text{eff}}(\omega) = \frac{n_{\text{eff}}^2}{\mu_0}
\]
\[
\mu_{\text{eff}}(\omega) = \mu_0.
\] (17)
The time-domain version of the frequency-dependent \(\varepsilon_{\text{eff}}\) can now be easily found by employing a VF procedure [23] to obtain an \(N\)th-order pole–residue partial fraction expansion
\[
\varepsilon_{\text{eff}}(\omega) = \varepsilon_\infty + \sum_{k=1}^{N} \frac{R_k}{j \omega - p_k}
\] (18)
which can include complex or purely real pole–residues. In case that these are complex, the complex conjugate of the pair must also appear in the expansion. Now, following the methodology of [24], we introduce a set of polarization currents \(\vec{J}_k(\omega)\) each one related to the E-field in FD and in TD, respectively, by
\[
\vec{J}_k(\omega) = \frac{j \omega R_k}{j \omega - p_k} \vec{E}(\omega)
\] (19)
\[
d \vec{J}_k(t) - p_k \vec{J}_k(t) = R_k \frac{d \vec{E}(t)}{dt}
\] (20)
which are plugged into Maxwell equations in TD to end up with
\[
-\nabla \times \vec{E} = \mu_0 \frac{\partial \vec{H}}{\partial t}
\] (21a)
\[
\nabla \times \vec{H} = \sum_{k=1}^{N} \vec{J}_k + \varepsilon_\infty \frac{\partial \vec{E}}{\partial t}.
\] (21b)

VI. IMPLEMENTATION INTO SGBC

The SGBC method introduced in [14] was born as a robustly stable subcell alternative of NIBC to find the tangential electric fields at each side of the thin slab, as a function of the magnetic fields in the adjacent host medium. It combines two methods: 1) a CNTD method in 1-D, to find the transversal EM solution within the slab, which is finely meshed to account for the fields variation inside and 2) the usual 3D Yee-FDTD method to solve the exterior problem coarsely discretized according to the desired resolution. A proper HIE algorithm is used to connect both methods at the slab boundaries. The unconditionally stable nature of CNTD and the natural HIE scheme we employ allows us to choose the time-step to meet the stability criterion just depending on the outer coarser mesh size, without compromising the computational affordability of the method.

The method described in [14] for nondispersive media can be extended to dispersive ones [15], as described next in a simplified manner. For this, let us assume a nonmagnetic pure homogeneous SGB medium, meshed with a uniform space-step \(\Delta_{\text{fine}}\). To find the CNTD scheme used inside, we start from the usual FDTD scheme for (20) and (21) to find
\[
J_{i,k}^n = \kappa_k J_{i,k}^{n-1} + \beta_k (E_i^n - E_i^{n-1}) \quad \forall k = 1, \ldots, N
\] (22)
\[
E_i^{n+1} = C_a E_i^n + C_b \left(J_{i-\frac{1}{2}}^{n+\frac{1}{2}} - H_{i-\frac{1}{2}}^{n+\frac{1}{2}}\right)
\]
\[
- C_j \text{Re} \sum_{k=1}^{N} (1 + \kappa_k) J_{i,k}^n
\] (23a)
\[
H_{i+\frac{1}{2}}^{n+\frac{1}{2}} = D_a H_{i+\frac{1}{2}}^{n-\frac{1}{2}} + D_b (E_{i+\frac{1}{2}}^{n} - E_{i+\frac{1}{2}}^{n-1})
\] (23b)
where the coefficients \(C_a, C_b, D_a, D_b, C_j, \beta_k, \kappa_k\) and \(\kappa_k\) are
\[
C_a = \frac{2 \varepsilon_\infty + \Lambda - \sigma \Delta t}{2 \varepsilon_\infty + \Lambda + \sigma \Delta t}
\]
\[
C_b = \frac{2 \Delta t / \Delta_{\text{fine}}}{2 \varepsilon_\infty + \Lambda + \sigma \Delta t}
\]
\[
D_a = 1
\]
\[
D_b = \frac{2 \Delta t / \Delta_{\text{fine}}}{2 \mu_0}
\]
\[
C_j = \frac{C_b}{2 \Delta_{\text{fine}}}
\] (24)
surrounding media, are built in the same manner given in [14] used inside the slab, to the usual FDTD equations, used in the

Fig. 8. Equivalent dielectric bulk parameters for the material of Fig. 2(a) with a thickness of 100 μm.

with

\[ \Lambda = \text{Re} \sum_{k=1}^{N} \beta_k \Delta t \]

\[ \beta_k = \frac{R_k}{1 - \rho_k \Delta t/2} \quad \kappa_k = \frac{1 + \rho_k \Delta t/2}{1 - \rho_k \Delta t/2} \]  \hspace{1cm} (25)

Now, the CNTD algorithm [15] is built from (23), by colo-

cating the H- and E-fields at integer time-steps, with the help of a time average for the right-hand side to yield

\[ E_{i+1}^{n+1} = C_a E_i^n + \frac{C_b}{2} \left( H_{i+\frac{1}{2}}^n - H_{i+\frac{1}{2}}^{n+1} + H_{i-\frac{1}{2}}^{n+1} - H_{i-\frac{1}{2}}^n \right) \]

\[ - C_J \text{Re} \sum_{k=1}^{N} (1 + \kappa_k) J_k^n \]  \hspace{1cm} (26)

\[ H_{i+\frac{1}{2}}^{n+1} = D_a H_{i+\frac{1}{2}}^n + \frac{D_b}{2} (E_i^n - E_{i+1}^{n+1} + E_{i+1}^{n+1} - E_{i+1}^n) \]  \hspace{1cm} (27)

and leaving (23a) untouched.

Now extracting \( H^{n+1} \) from (27) and inserting it into (26), a fully consistent algorithm with the space positions of \( E \) and \( H \) staggered in space, as in the usual Yee-Scheme, is yielded, but evaluated at colocated integer time-steps. After some algebra, a tridiagonal system of equations is found for the \( E \)-fields

\[ a E_{i-1}^{n+1} + b E_i^{n+1} + c E_{i+1}^{n+1} = d_i^n \]  \hspace{1cm} (28)

with

\[ a = -\frac{C_b D_b}{4} \quad b = 1 - a - c \]

\[ d_i^n = \frac{C_b D_b}{4} \left( E_{i-1}^n + E_{i+1}^n \right) + \left( C_a - \frac{C_b D_b}{2} \right) E_i^n + \frac{C_b}{2} (1 + D_a) \left( H_{i-\frac{1}{2}}^n - H_{i+\frac{1}{2}}^n \right) - C_J J_i^n. \]  \hspace{1cm} (29)

Note that the \( H \)-fields are advanced explicitly by (27) from the \( E \)-fields. The HIE conditions to connect the CNTD equations, used inside the slab, to the usual FDTD equations, used in the surrounding media, are built in the same manner given in [14] (not given here for simplicity).

VII. VALIDATION

A canonical validation of this method is presented here. It computes the SE of the indefinite thin panel of the prepreg copper mesh [Fig. 2(a)] previously analyzed in Section IV-A. The constitutive parameters of the equivalent negative-permittivity material have been extracted from the S-parameters found with Wait’s model (Fig. 8), assuming a thickness \( h_t = 100 \mu m \), and vector-fit with a tenth-order pole–residue expansion (see Table I). We have simulated a thin-slab of this material under plane-wave TE incidence, with the HIE CNTD method described previously, taking ten cells along its thickness. Results for its SE are shown in Fig. 9. They perfectly match with the analytical ones and reasonably agree with experimental measurements from [4] (S1).

VIII. CONCLUSION

In this paper, we have presented a full road map to start from the microscopic nature of a composite multilayered thin panel and end into a macroscopic TD model to be simulated by FDTD.

In the first part, we have revisited Holloway’s and Wait’s model and discussed some of their limitations, taking profit of low-level simulations of their fine structure. While both methods reasonably agree in the asymptotic low-frequency regime, differences appear at high frequency. We have shown that for nondense structures, Holloway’s model does not
replicate the simulated behavior at high frequencies, whereas Wait’s assumptions provide a more realistic model. On the other hand, for structures densely stacked along the panel thickness, like the CFC test-case (with the homogeneous assumption), the material has a classical conductorlike skin-effect behavior, properly predicted by Holloway’s model and falling out of Wait’s hypotheses. Finally, for intermediate structures, the behavior is a combination of both models and still requires a deeper study.

In the second part of this paper, we have extended the SGBC procedure to deal with the dispersive nature of thin panels, assuming that their scattering parameters are found with the techniques given in the first part. A parameter extraction procedure has been presented, and a time-domain implementation of the dispersive constitutive parameters has been described. For this, the CNTD method used by SGBC has been extended. Finally, the whole road map has been applied to one of the test cases used in the first part to prove the feasibility of this approach.

ACKNOWLEDGMENT

The authors would like to thank A. R. Lora for helping with the drawing of the thin-panel models used in Section IV.

REFERENCES


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